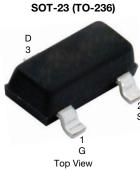
SQ2364EES

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Vishay Siliconix

Automotive N-Channel 60 V (D-S) 175 °C MOSFET



Marking code: 9Jxxx

PRODUCT SUMMARY				
V _{DS} (V)	60			
$R_{DS(on)} (\Omega)$ at $V_{GS} = 1.5 V$	0.245			
I _D (A)	2			
Configuration	Single			
Package	SOT-23			

FEATURES

- TrenchFET[®] power MOSFET
- AEC-Q101 qualified
- 100 % Rg and UIS tested
- Typical ESD protection 800 V
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>



HALOGEN

FREE

Com/doc?99912

ORDERING INFORMATION				
Package	SOT-23			
Lead (Pb)-free and halogen-free	SQ2364EES-T1 (for detailed order number please see <u>www.vishay.com/doc?79771</u>)			

ABSOLUTE MAXIMUM RATINGS (T _C = 25 °C, unles	s otherwise noted)		
PARAMETER		SYMBOL	LIMIT	UNIT	
Drain-source voltage		V _{DS}	60	V	
Gate-source voltage		V _{GS}	± 8	V	
Continuous drain current	T _C = 25 °C	- I _D -	2		
	T _C = 125 °C		1.3		
Continuous source current (diode conduction)		I _S	2	А	
Pulsed drain current ^a		I _{DM}	8		
Single pulse avalanche current	L = 0.1 mH	I _{AS}	5		
Single pulse avalanche energy		E _{AS}	1.25	mJ	
Maximum power dissipation ^a	T _C = 25 °C	PD	3	W	
	T _C = 125 °C		1	vv	
Operating junction and storage temperature range	ge	T _J , T _{stg}	-55 to +175	°C	

THERMAL RESISTANCE RATINGS				
PARAMETER		SYMBOL	LIMIT	UNIT
Junction-to-ambient	PCB mount ^b	R _{thJA}	166	°C/W
Junction-to-foot (drain)		R _{thJF}	50	C/W

Notes

a. Pulse test; pulse width $\leq 300~\mu s,~duty~cycle \leq 2~\%$

b. When mounted on 1" square PCB (FR4 material)

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SPECIFICATIONS ($T_C = 25 \ ^{\circ}C$,		-					· · · · ·	
PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNIT	
Static	-	T						
Drain-source breakdown voltage	V _{DS}		= 0, I _D = 250 μA	60	-	-	v	
Gate-source threshold voltage	V _{GS(th)}	V _{DS} =	: V _{GS} , I _D = 250 μΑ	0.46	0.6	1	v	
Gate-source leakage	I _{GSS}	50	$V_{DS}=0~V,~V_{GS}=\pm~3~V$		-	± 100	nA	
Cate Source reakage	'655	-	= 0 V, V _{GS} = ± 8 V	-	-	± 5.5		
Zero gate voltage drain current		$V_{GS} = 0 V$	V _{DS} = 60 V	-	-	1	μA	
	I _{DSS}	$V_{GS} = 0 V$	V_{DS} = 60 V, T_J = 125 °C	-	-	50	μΛ	
		$V_{GS} = 0 V$	V_{DS} = 60 V, T_{J} = 175 °C	-	-	150	1	
On-state drain current ^a	I _{D(on)}	$V_{GS} = 4.5 V$	$V_{DS} \ge 5 V$	2	-	-	Α	
Drain-source on-state resistance ^a		$V_{GS} = 4.5 V$	$I_D = 2 \text{ A}, \text{T}_\text{J} = 25 \ ^\circ\text{C}$	-	0.190	0.240		
	Р	$V_{GS} = 4.5 V$	I _D = 2 A, T _J = 125 °C	-	-	0.460	Ω	
	R _{DS(on)}	$V_{GS} = 4.5 V$	I _D = 2 A, T _J = 175 °C	-	-	0.600	Ω	
		$V_{GS} = 1.5 V$	I _D = 2 A	-	0.195	0.245		
Forward transconductance b	9 _{fs}	V _{DS}	= -15 V, I _D = 1 A	-	8.8	-	S	
Dynamic ^b	•	•			•	•		
Input capacitance	C _{iss}			-	263	330		
Output capacitance	C _{oss}	$V_{GS} = 0 V$	V _{DS} = 25 V, f = 1 MHz	-	28	35	pF	
Reverse transfer capacitance	C _{rss}			-	15	19		
Total gate charge ^c	Qg			-	2	2.5		
Gate-source charge ^c	Q _{gs}	V _{GS} = 4.5 V	V _{DS} = 30 V, I _D = 1.5 A	-	0.3	-	nC	
Gate-drain charge ^c	Q _{gd}			-	0.6	-	1	
Gate resistance	Rg	f = 1 MHz		2.5	4.1	6.6	Ω	
Turn-on delay time ^c	t _{d(on)}			-	6	7.2		
Rise time ^c	t _r	$\label{eq:VDD} \begin{array}{l} V_{\text{DD}} = 30 \; V, \; R_{\text{L}} = 15 \; \Omega \\ I_{\text{D}} \cong 1.5 \; A, \; V_{\text{GEN}} = 10 \; V, \; R_{\text{g}} = 1 \; \Omega \end{array}$		-	11	14	ns	
Turn-off delay time ^c	t _{d(off)}			-	26	32		
Fall time ^c	t _f			-	13	16		
Source-Drain Diode Ratings and Char	acteristics ^b						1	
Pulsed current ^a	I _{SM}			-	-	8	Α	
Forward voltage	V _{SD}	le le	$= 2 \text{ A}, \text{ V}_{GS} = 0$	-	0.8	1.2	V	

Notes

a. Pulse test; pulse width \leq 300 µs, duty cycle \leq 2 %

b. Guaranteed by design, not subject to production testing

c. Independent of operating temperature

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

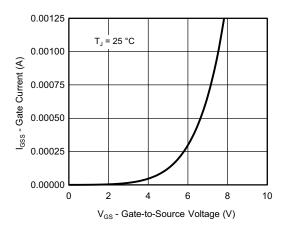
2



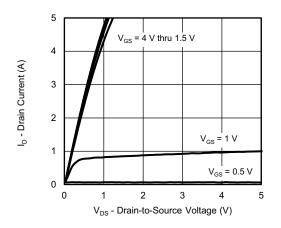
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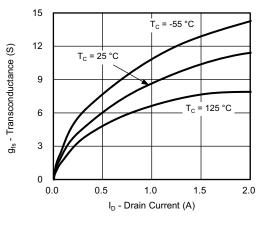
TYPICAL CHARACTERISTICS ($T_A = 25 \text{ °C}$, unless otherwise noted)



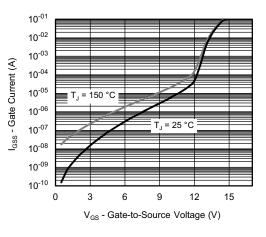
Gate Current vs. Gate-Source Voltage



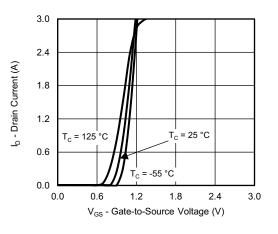
Output Characteristics



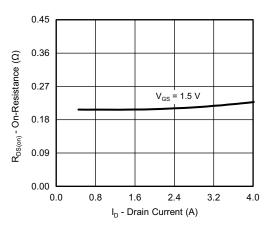
Transconductance



Gate Current vs. Gate-Source Voltage



Transfer Characteristics



On-Resistance vs. Drain Current

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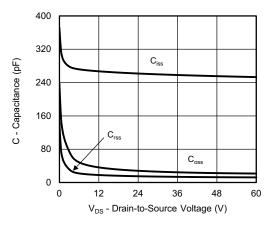
3 s. contact: automostechs Document Number: 75975

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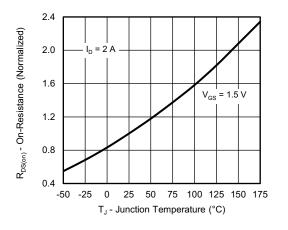


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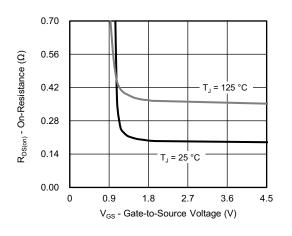
TYPICAL CHARACTERISTICS ($T_A = 25 \text{ °C}$, unless otherwise noted)



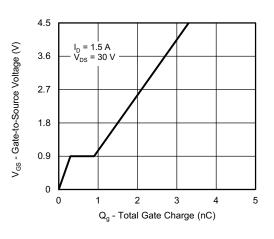
Capacitance



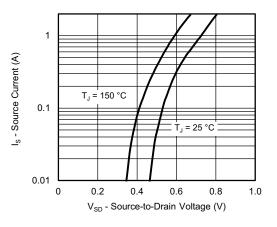
On-Resistance vs. Junction Temperature



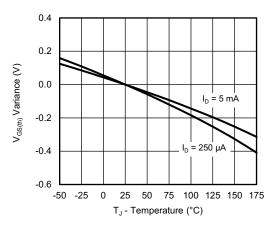
On-Resistance vs. Gate-Source Voltage



Gate Charge



Source-Drain Diode Forward Voltage



Threshold Voltage

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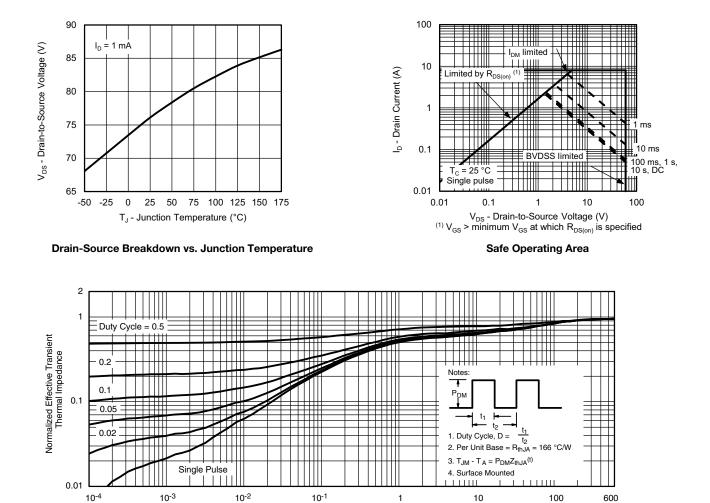
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TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)



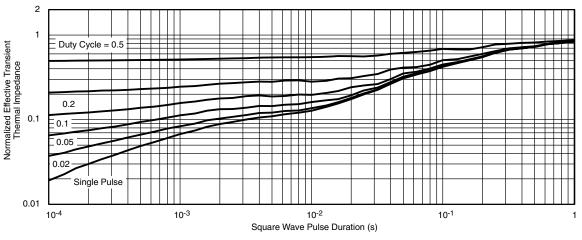
Square Wave Pulse Duration (s) Normalized Thermal Transient Impedance, Junction-to-Ambient



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THERMAL RATINGS (T_A = 25 °C, unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Foot

Note

The characteristics shown in the two graphs

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- Normalized Transient Thermal Impedance Junction-to-Ambient (25 °C)
- Normalized Transient Thermal Impedance Junction-to-Foot (25 °C)

are given for general guidelines only to enable the user to get a "ball park" indication of part capabilities. The data are extracted from single pulse transient thermal impedance characteristics which are developed from empirical measurements. The latter is valid for the part mounted on printed circuit board - FR4, size 1" x 1" x 0.062", double sided with 2 oz. copper, 100 % on both sides. The part capabilities can widely vary depending on actual application parameters and operating conditions

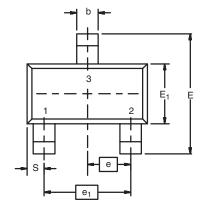
Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package / tape drawings, part marking, and reliability data, see www.vishay.com/ppg?75975.



Package Information

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SOT-23 (TO-236): 3-LEAD







Dim	MILLIN	METERS	INCHES		
	Min	Max	Min	Мах	
Α	0.89	1.12	0.035	0.044	
A ₁	0.01	0.10	0.0004	0.004	
A ₂	0.88	1.02	0.0346	0.040	
b	0.35	0.50	0.014	0.020	
С	0.085	0.18	0.003	0.007	
D	2.80	3.04	0.110	0.120	
E	2.10	2.64	0.083	0.104	
E ₁	1.20	1.40	0.047	0.055	
е	0.95 BSC		0.0374 Ref		
e ₁	1.90 BSC		0.0748 Ref		
L	0.40	0.60	0.016	0.024	
L ₁	0.64 Ref		0.025 Ref		
S	0.50 Ref		0.020 Ref		
q	3°	8°	3°	8°	



Application Note 826

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RECOMMENDED MINIMUM PADS FOR SOT-23



Recommended Minimum Pads Dimensions in Inches/(mm)

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Revision: 01-Jan-2024